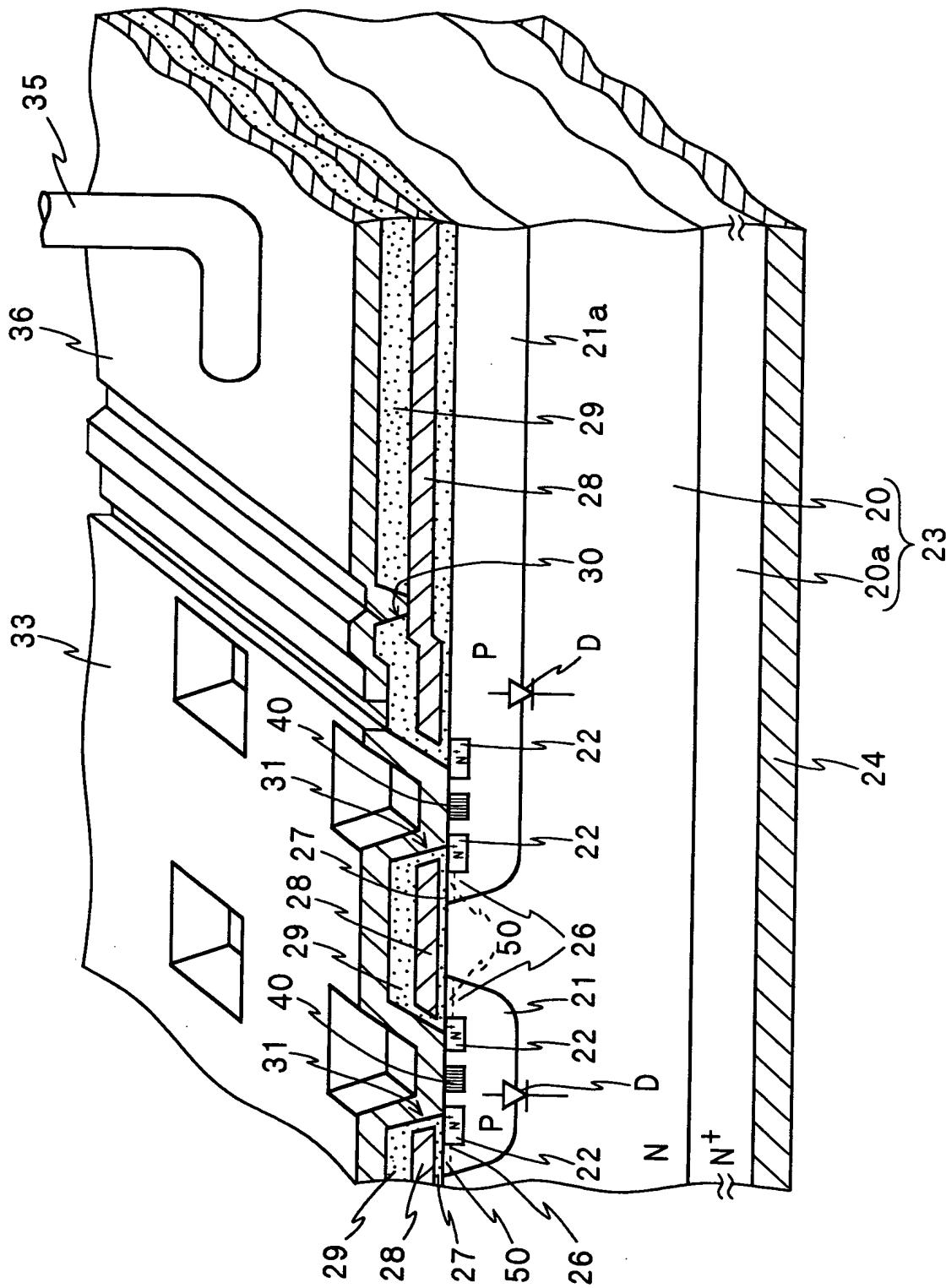




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REPLACEMENT SHEET

FIG. 1

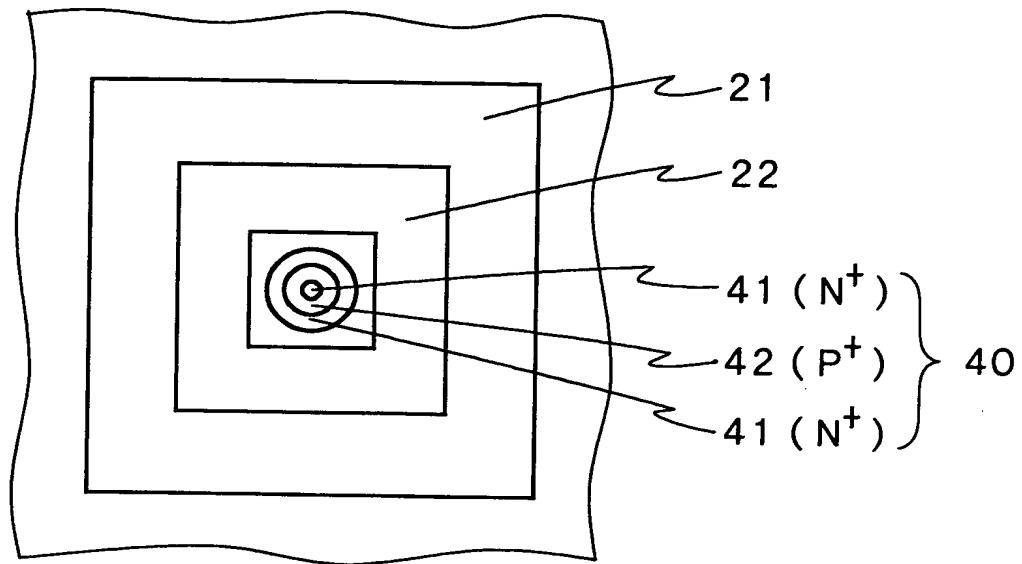


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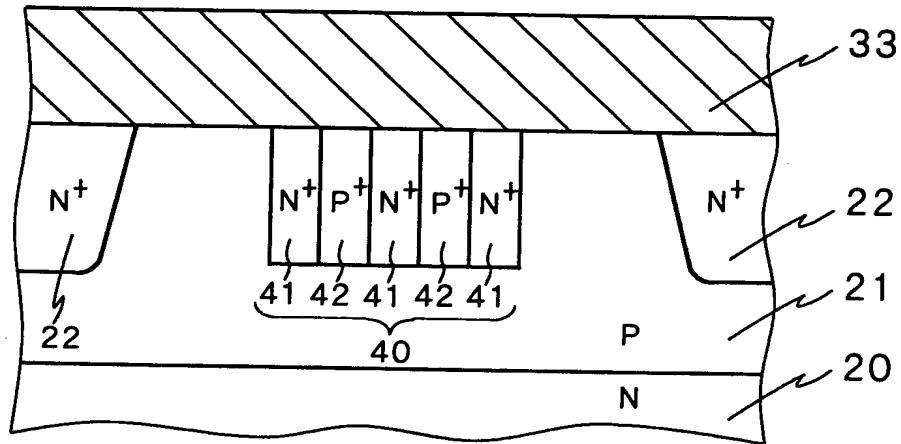
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F I G . 2 A



F I G . 2 B





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FIG. 3

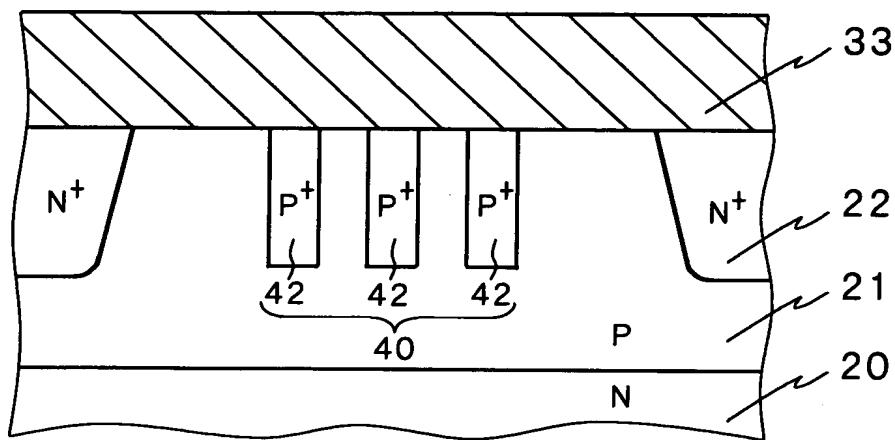


FIG. 4
PRIOR ART

